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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

Applicant(s) Yusheng Zhao et al.

Filing Date

Group

37 CFR 1.98(b)

U.S. PATENTS DOCUMENTS

EXAMINER INITIAL	PATENT NUMBER	ISSUE DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
<i>[Signature]</i>	4 1 8 7 0 8 3	02/05/80	Roger J. Wedlake et al.	51	307	02/16/78

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL	PATENT NUMBER	ISSUE DATE	COUNTRY	CLASS	SUB CLASS	Translation YES NO

OTHER DOCUMENTS (Including Author, Title, Date, Place of Publication)

<i>[Signature]</i>	E. Knittle, R. B. Kaner, R. Jeanloz, and M. L. Cohen, "High-Pressure Synthesis, Characterization, and Equation of State of Cubic C-BN Solid Solutions," Physical Review B, Vol. 51, No. 18, pp. 149-156, May 1, 1995
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	Wataru Utsumi, S. Nakano, K. Kimoto, T. Okada, M. Isshiki, T. Taniguchi, K. Funakoshi, M. Akaishi, and O. Shimomura, "In Situ X-Ray and TEM Observations on the Phase Transitions of BC₂N Under Static High Pressures," Proceedings of AIRAPPT-18, Beijing, p. 186, 2001
<i>[Signature]</i>	Jianyu Huang, Yuntian T. Zhu, and Hirotaro Mori, "Structure and Phase Characteristics of Amorphous Boron-Carbon-Nitrogen Under High Pressure and High Temperature," J. Mater. Res., Vol. 16, No. 4, pp. 1178-1184, April 2001
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EXAMINER:

DATE CONSIDERED:

5-12-05

*EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.